



ATP207

N-Channel Power MOSFET 40V, 65A, 9.1mΩ, Single ATPAK

ON Semiconductor®

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Features

- Low ON-resistance
- 4.5V drive
- Halogen free compliance
- Large current
- Slim package
- Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		40	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		65	A
Drain Current (PW≤10μs)	I _{DP}	PW≤10μs, duty cycle≤1%	195	A
Allowable Power Dissipation	P _D	T _c =25°C	50	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	E _{AS}		35	mJ
Avalanche Current *2	I _{AV}		33	A

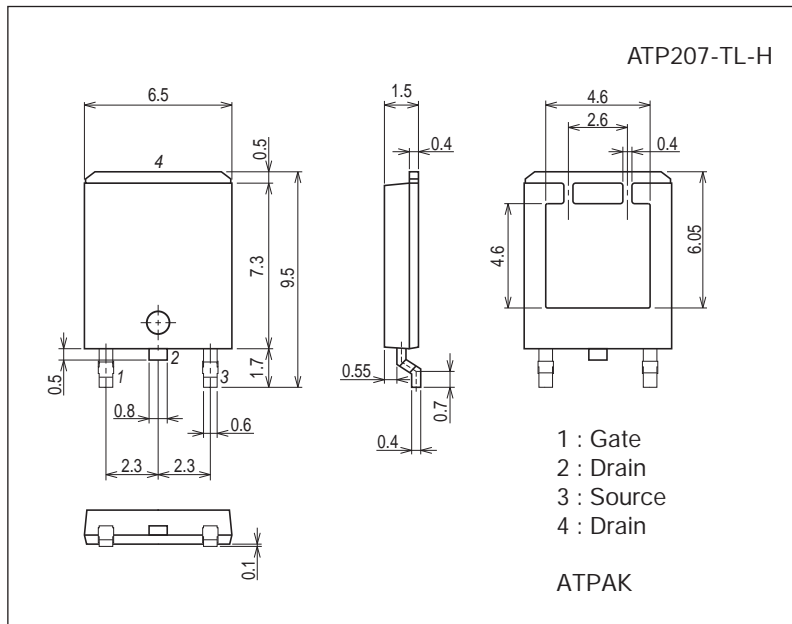
Note : *1 V_{DD}=10V, L=50μH, I_{AV}=33A
*2 L≤50μH, Single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

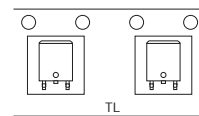
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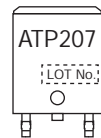
Product & Package Information

- Package : ATPAK
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

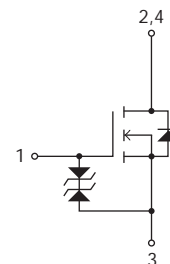
Packing Type: TL



Marking



Electrical Connection

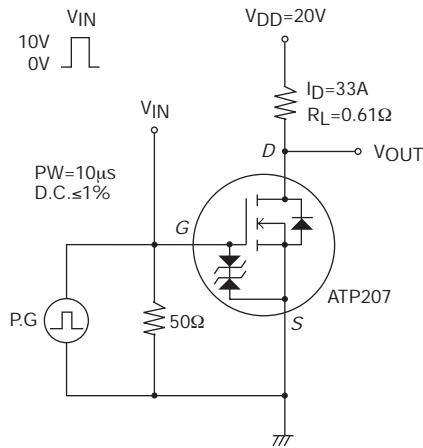


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Electrical Characteristics at Ta=25°C

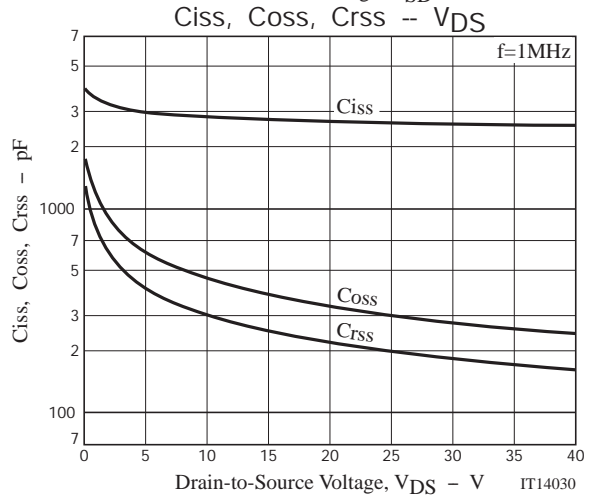
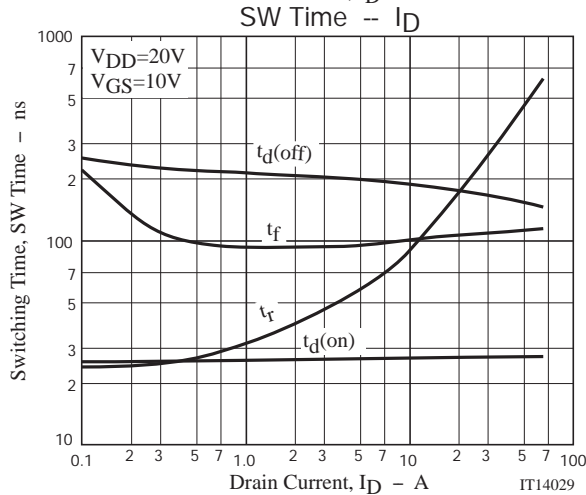
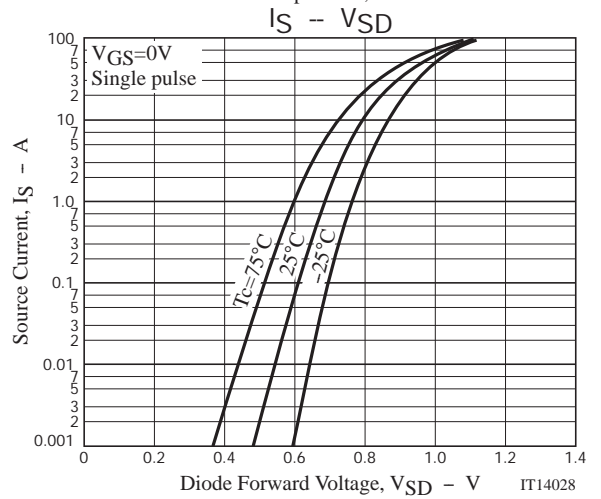
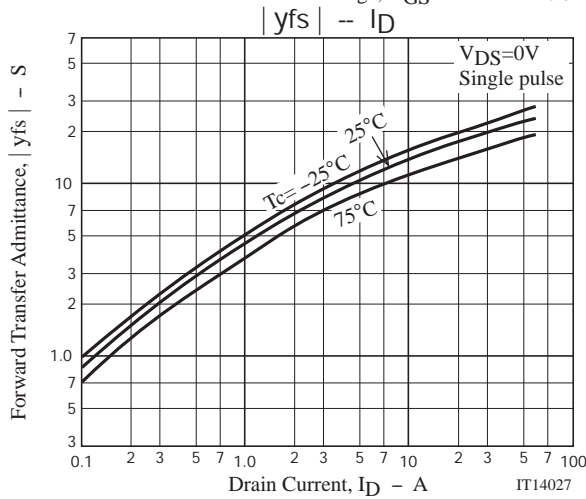
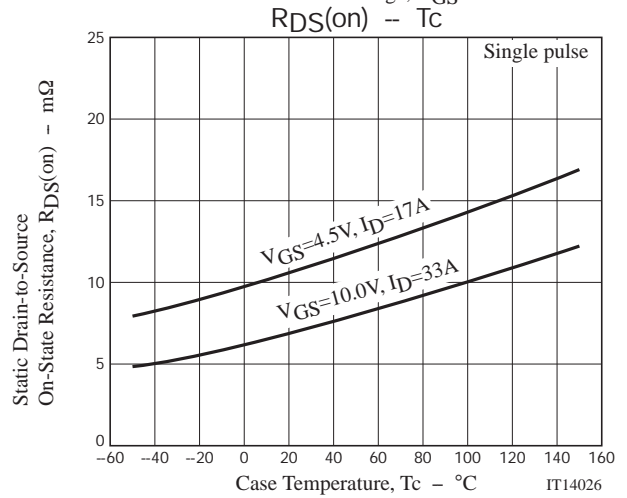
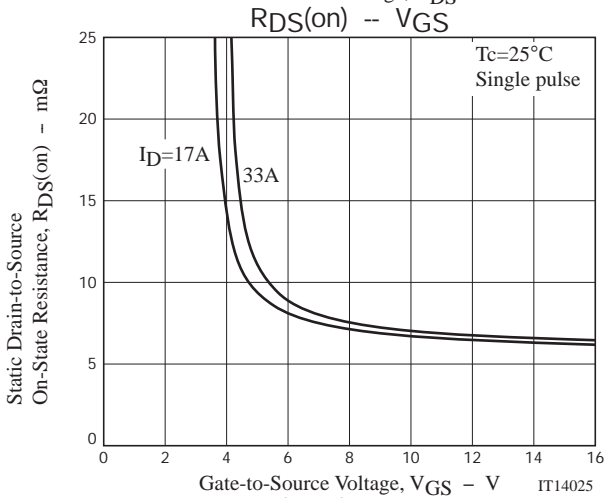
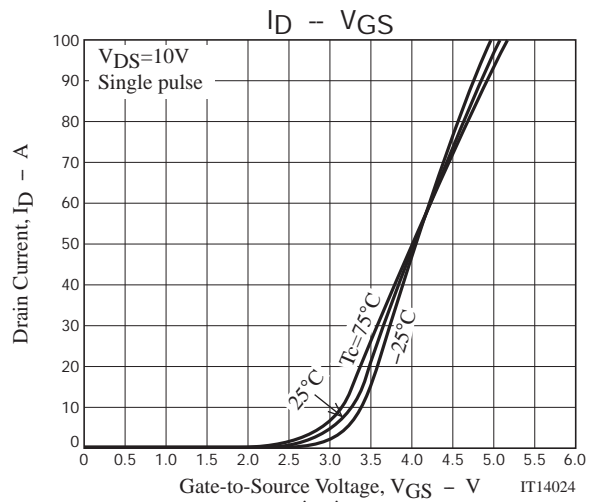
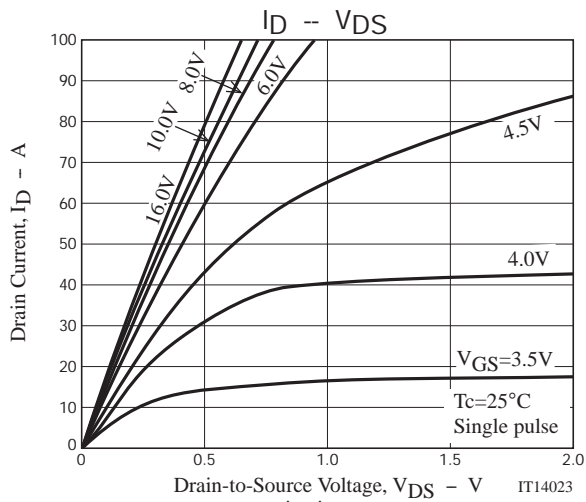
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	40			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.5		2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =33A	12	20		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =33A, V _{GS} =10V		7	9.1	mΩ
	R _{DS(on)2}	I _D =17A, V _{GS} =4.5V		11	15.5	mΩ
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz		2710		pF
Output Capacitance	C _{oss}			330		pF
Reverse Transfer Capacitance	C _{rss}			220		pF
Turn-ON Delay Time	t _{d(on)}			27		ns
Rise Time	t _r	See specified Test Circuit.		290		ns
Turn-OFF Delay Time	t _{d(off)}			170		ns
Fall Time	t _f			110		ns
Total Gate Charge	Q _g			54		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =20V, V _{GS} =10V, I _D =65A		14		nC
Gate-to-Drain "Miller" Charge	Q _{gd}			11		nC
Diode Forward Voltage	V _{SD}		I _S =65A, V _{GS} =0V		1.0	1.2

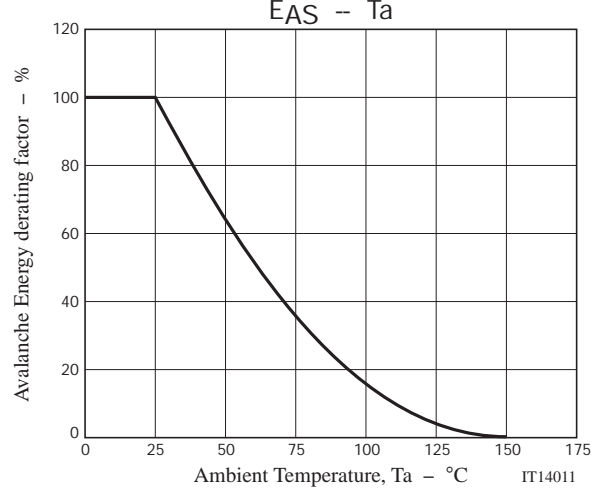
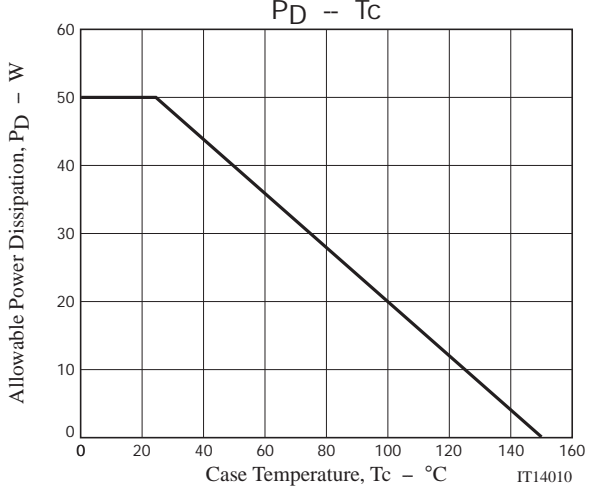
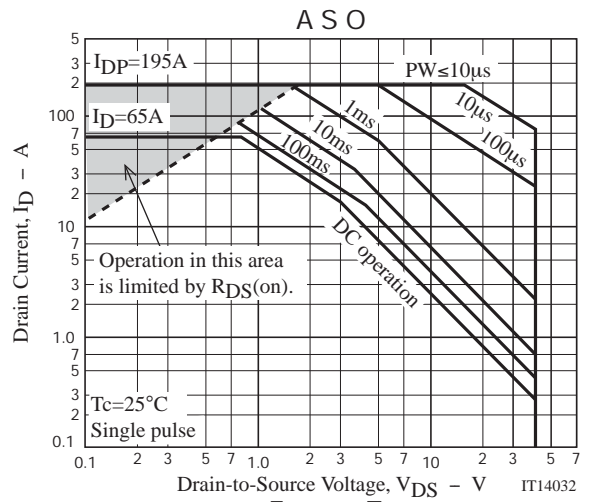
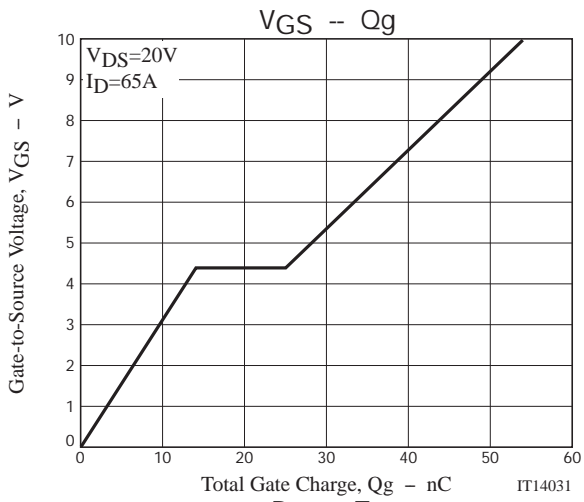
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
ATP207-TL-H	ATPAK	3,000pcs./reel	Pb Free and Halogen Free





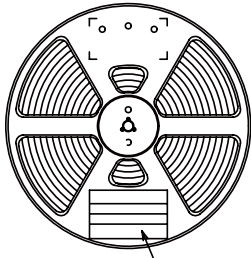
Taping Specification

ATP207-TL-H

1. Packing Format (TL)

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	INNER BOX SD-C-18	OUTER BOX SD-A-18
ATPAK	ATP	3,000	3,000	15,000	1 reels contained Dimensions:mm (external) 340×340×28	5 inner boxes contained Dimensions:mm (external) 355×355×165

Packing method



Reel label

Reel label, Inner box label
(unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

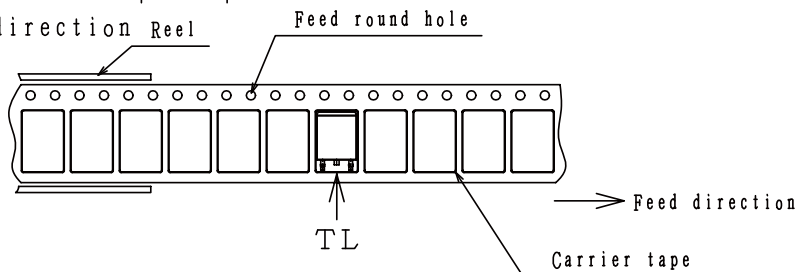
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction Reel



The one electrode terminals on feed hole side...TL

ATP207

Outline Drawing

ATP207-TL-H



Land Pattern Example



Note on usage : Since the ATP207 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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